## VS-VSKDF400/06PbF

**Vishay Semiconductors** 

### FRED Pt<sup>®</sup> Gen 4 Doubler Ultrafast Diode, 400 A (INT-A-PAK Power Modules)



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<b>FEATURES</b>	
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- Gen 4 FRED Pt<sup>®</sup> dices technology
- Ultrasoft reverse recovery characteristics
- Low I<sub>RRM</sub> and reverse recovery charge
- Very low forward voltage drop
- 175 °C operating junction temperature
- UL approved file E78996 for application with maximum case temperature up to 140 °C
- Large creepage distances
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

Gen 4 FRED Pt technology, state of the art, ultra low  $V_F$ , soft switching optimized for IGBT F/W diode.

The minimized conduction loss, optimized storage charge, and low recovery current, minimized the switching losses and reduce the over dissipation in the switching element and snubbers.

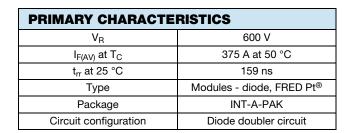
ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V <sub>R</sub>		600	V	
Continuous forward current	١ <sub>F</sub>	T <sub>C</sub> = 25 °C	540		
Continuous forward current		T <sub>C</sub> = 80 °C	400	А	
Single pulse forward current	I <sub>FSM</sub>	$t_p$ = 10 ms, 50 Hz, sine half wave, initial T <sub>J</sub> = 175 °C	4140		
Maximum power dissipation	р	T <sub>C</sub> = 25 °C	1153	w	
	PD	T <sub>C</sub> = 90 °C	653	vv	
Operating junction temperature range	TJ		-40 to +175	°C	
Storage temperature range	T <sub>Stg</sub>		-40 to +150	U	
RMS insulation voltage	tion voltage V <sub>INS</sub> 50 Hz, circuit to base, all terminals shorted, t = 1 s		3500	V	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 500 μA	600	-	-	
	V <sub>FM</sub>	I <sub>F</sub> = 200 A	-	1.28	-	
Forward voltage drop		I <sub>F</sub> = 400 A	-	1.51	1.67	V
Forward voltage drop		I <sub>F</sub> = 200 A, T <sub>J</sub> = 150 °C	-	1.04	-	
		I <sub>F</sub> = 400 A, T <sub>J</sub> = 150 °C	-	1.35	-	
Reverse leakage current	I <sub>RM</sub>	V <sub>R</sub> = 600 V	-	12	-	μA
		$T_{\rm J} = 150 \ ^{\circ}\text{C}, \ V_{\rm R} = 600 \ \text{V}$	-	2.2	-	mA

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 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t <sub>rr</sub>	$T_J = 25 \ ^{\circ}C$	I <sub>F</sub> = 150 A dI/dt = 200 A/μs V <sub>R</sub> = 400 V	-	159	-	ns
		T <sub>J</sub> = 125 °C		-	320	-	
Peak recovery current	Irr	T <sub>J</sub> = 25 °C		-	14	-	A
		T <sub>J</sub> = 125 °C		-	32	-	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	0.9	-	μC
		T <sub>J</sub> = 125 °C		-	4.3	-	

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum thermal resistance, junction to case per leg					
Typical thermal resistance, case to heat sink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	0.035	K/W	
Mountingto heat sinktorque ± 10 %busbar		A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow the spread of the compound.	4 to 6	Nm	
Approximate weight			200 7.1	g oz.	
Case style			INT-A-PAK	02.	

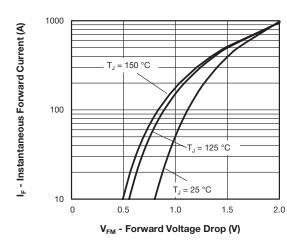


Fig. 1 - Typical Forward Voltage Drop Characteristics

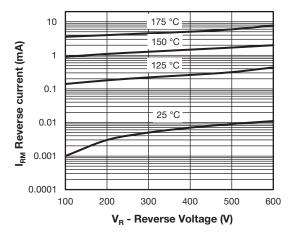


Fig. 2 - Typical Value of Reverse Current vs. Reverse Voltage



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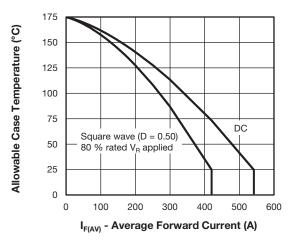


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current

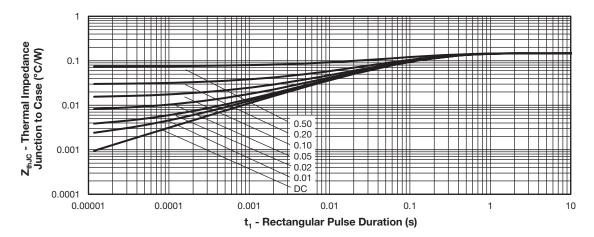
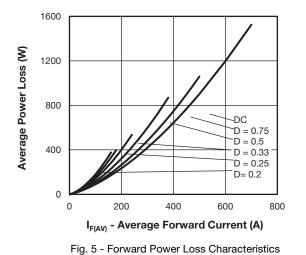


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



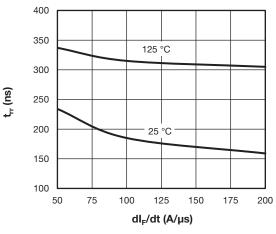


Fig. 6 - Typical Reverse Recovery Time vs. dI\_F/dt I\_{FM} = 150 A, V\_R = 400 V

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125 °C

100

25 °C

125

dl<sub>F</sub>/dt (A/µs)

Fig. 8 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

I<sub>FM</sub> = 150 A, V<sub>R</sub> = 400 V

150

175

200

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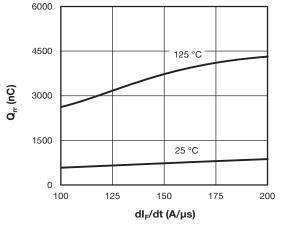
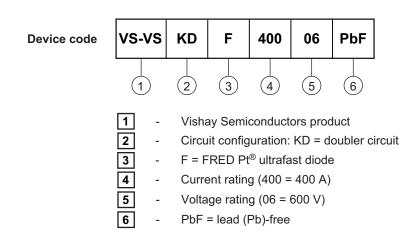


Fig. 7 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt  $I_{FM} = 150 \text{ A}, V_{R} = 400 \text{ V}$ 

#### **ORDERING INFORMATION TABLE**



35

30

25 20

15

10

5

0

50

75

I<sub>rr</sub> (A)

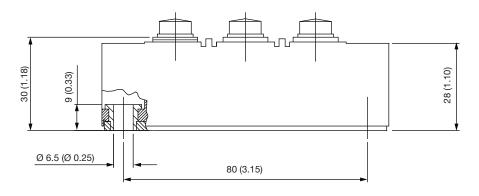
CIRCUIT CONFIGURATION					
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING			
Diode doubler circuit	KD	KD reversed polarity			

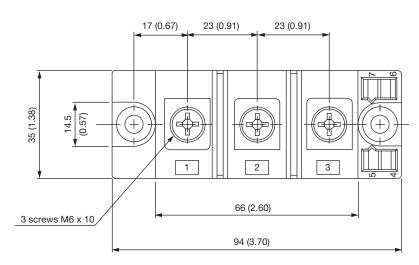


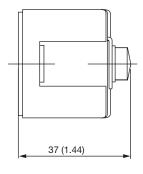
## VS-VSKDF400/06PbF

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**DIMENSIONS** in millimeters (inches)







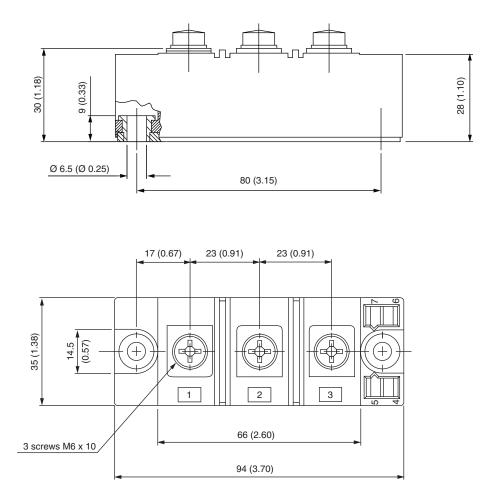


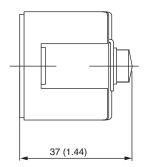
# **Outline Dimensions**

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## **INT-A-PAK DBC**

#### **DIMENSIONS** in millimeters (inches)







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